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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

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October 2014

KSA1013 PNP Epitaxial Silicon Transistor

Features

- Color TV Audio Output
- · Color TV Vertical Deflection Output



Ordering Information

Part Number	Top Mark Package		Packing Method		
KSA1013YBU			Bulk		
KSA1013OBU	A1013	TO-92 3L	Duik		
KSA1013YTA			Ammo		
KSA1013OTA			Ammo		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-160	V
V _{CEO}	Collector-Emitter Voltage	-160	V
V _{EBO}	Emitter-Base Voltage	-6	V
I _C	Collector Current	-1	Α
I _B	Base Current	-0.5	Α
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
D	Power Dissipation	900	mW
P_{D}	Derate Above T _A = 25°C	7.2	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	139	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current	$V_{CB} = -150 \text{ V}, I_{E} = 0$			-1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = -6 \text{ V}, I_{C} = 0$			-1	μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{ mA}, I_B = 0$	-160			V
h _{FE}	DC Current Gain	$V_{CE} = -5 \text{ V}, I_{C} = -200 \text{ mA}$	60		320	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$		\	-1.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -5 \text{ V}, I_{C} = -5 \text{ mA}$	-0.45		-0.75	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -5 \text{ V}, I_{C} = -200 \text{ mA}$	15	50		MHz
C _{ob}	Output Capacitance	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz			35	pF

h_{FE} Classification

Classification	R	0	Υ		
h _{FE}	60 ~ 120	100 ~ 200	160 ~ 320		

Typical Performance Characteristics

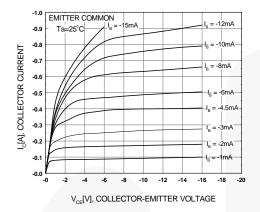


Figure 1. Static Characteristic

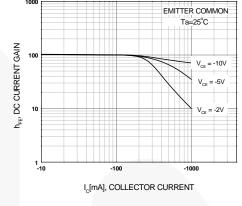


Figure 2. DC Current Gain

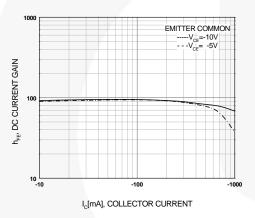


Figure 3. DC Current Gain

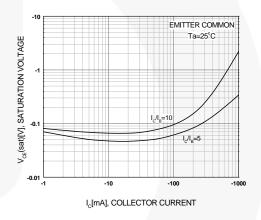


Figure 4. Collector-Emitter Saturation Voltage

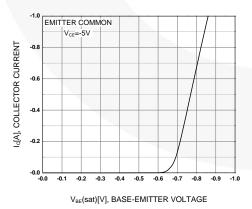


Figure 5. Base-Emitter On Voltage

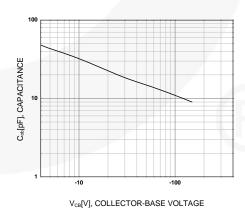


Figure 6. Collector Output Capacitance

Typical Performance Characteristics (Continued)

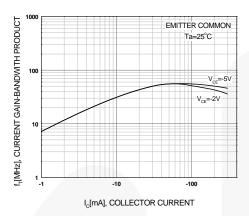


Figure 7. Current Gain Bandwidth Product

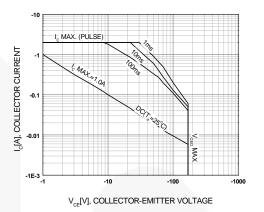
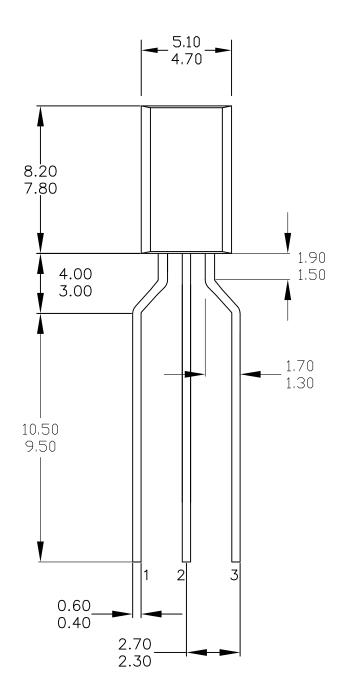
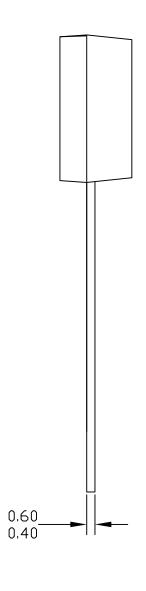
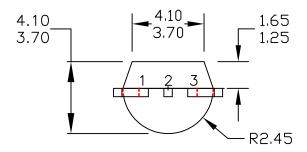


Figure 8. Safe Operating Area

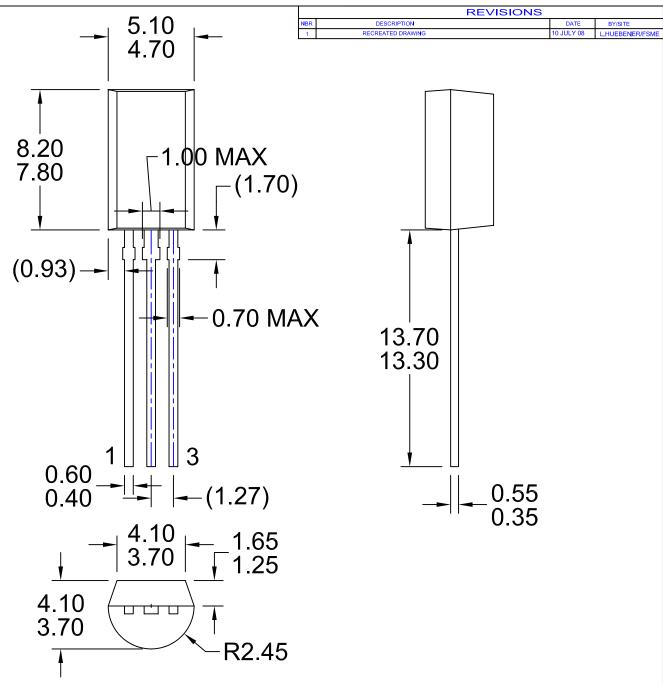






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DRAWN: L.HUEBENER	10 JULY 08	FAIF	२ C	HILE	2		
CHECKED: H.ALLEN	10 DEC 08	SEMIC		DUCTOF	₹тм		
APPROVED:		3LD, TO92L, 8MM TALL BODY					
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